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RF Exposure Evaluation Report

Report No.: CQASZ171001520EW-02

Applicant: SHENZHEN HUBSAN TECHNOLOGY CO., LTD.

Address of Applicant: 13th Floor, Bldg 1C, Shenzhen Software Industry Base, Xuefu Road, Nanshan

District, Shenzhen, China. 518054

SHENZHEN HUBSAN TECHNOLOGY CO., LTD. Manufacturer:

Address of 13th Floor, Bldg 1C, Shenzhen Software Industry Base, Xuefu Road, Nanshan

Manufacturer: District, Shenzhen, China. 518054

Dongguan Tengsheng Industrial Co., Ltd. **Factory:**

Address of Factory: A22# Luyi Street, Tianxin Village, Tangxia Town, Dongguan, China.

Equipment Under Test (EUT):

Product: HUBSAN X4 Desire Pro

Model No.: H216A **Brand Name: HUBSAN**

FCC ID: 2AN75-216ARX 47 CFR Part 1.1307 Standards: 47 CFR Part 1.1310

KDB447498D01 General RF Exposure Guidance v06

Date of Test: 2018-01-08 to 2018-01-12

Date of Issue: 2018-01-12 Test Result: PASS*

Tested By:

(Aaron Ma)

Reviewed By:

Owen Zhou)

Approved By:

The test report is effective only with both signature and specialized stamp, The result(s) shown in this report refer only to the sample(s) tested. Without written approval of CQA, this report can't be reproduced except in full.

^{*} In the configuration tested, the EUT complied with the standards specified above.



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2 Version

Revision History Of Report

Report No.	Version	Description	Issue Date	
CQASZ171001520EW-02	Rev.01	Initial report	2018-01-12	





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4 General Information

4.1 Client Information

Applicant:	SHENZHEN HUBSAN TECHNOLOGY CO., LTD.	
Address of Applicant:	13th Floor, Bldg 1C, Shenzhen Software Industry Base, Xuefu Road, Nanshan District, Shenzhen, China. 518054	
Manufacturer: SHENZHEN HUBSAN TECHNOLOGY CO., LTD.		
Address of Manufacturer:	13th Floor, Bldg 1C, Shenzhen Software Industry Base, Xuefu Road, Nanshan District, Shenzhen, China. 518054	
Factory: Dongguan Tengsheng Industrial Co., Ltd.		
Address of Factory:	A22# Luyi Street, Tianxin Village, Tangxia Town, Dongguan, China.	

4.2 General Description of EUT

Product Name:	HUBSAN X4 Desire Pro	
Model No.:	H216A	
Trade Mark:	HUBSAN	
Hardware version:	EA4000136-01	
Software version:	H216A-FC-V2.1.35	
Operation Frequency:	IEEE 802.11b/g/n(HT20): 2412MHz to 2462MHz	
	IEEE 802.11n(HT40): 2422MHz to 2452MHz	
Channel Numbers:	IEEE 802.11b/g, IEEE 802.11n HT20: 11 Channels	
	IEEE 802.11n HT40: 7 Channels	
Channel Separation:	5MHz	
Type of Modulation:	IEEE for 802.11b: DSSS(CCK,DQPSK,DBPSK)	
, ,	IEEE for 802.11g : OFDM(64QAM, 16QAM, QPSK, BPSK)	
	IEEE for 802.11n(HT20 and HT40) : OFDM (64QAM, 16QAM,	
	QPSK,BPSK)	
Sample Type:	portable production	
Test Software of EUT:	Atheros Radio Test 2 (provided by manufacturer)	
Antenna Type:	internal antenna with ipex connector	
Antenna Gain:	0.5dBi	
Power Supply:	Lithium ion batteries: DC7.6V, 750mAh	

Note: The EUT has two WIFI antennas, They are SISO and cannot be transmitted at the same time. Antenna 1 and antenna 2 have been tested, find test data of the antenna 1 is the worst case, only the worst case is recorded in the report.



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5 RF Exposure Evaluation

5.1 RF Exposure Compliance Requirement

5.1.1 Limits

According to FCC Part1.1310: The criteria listed in the following table shall be used to evaluate the environment impact of human exposure to radio frequency (RF) radiation as specified in part1.1307(b)

Table 1—LIMITS FOR MAXIMUM PERMISSIBLE EXPOSURE (MPE)

Frequency range (MHz)	Electric field strength (V/m)	Magnetic field strength (A/m)	Power density (mW/cm²)	Averaging time (minutes)				
(A) Limits for Occupational/Controlled Exposures								
0.3–3.0	614 1842/f	1.63 4.89/f	*(100) *(900/f²)	6				
30–300 300–1500	61.4	0.163	1.0 f/300	6 6				
1500-100,000			5	6				
(B) Limits for General Population/Uncontrolled Exposure								
0.3–1.34	614	1.63	*(100)	30				
1.34–30	824/f	2.19/f	*(180/f ²)	30				
30-300	27.5	0.073	0.2	30				
300–1500 1500–100,000			f/1500 1.0	30 30				

F= Frequency in MHz

Friis Formula

Friis transmission formula: $Pd = (Pout*G)/(4*Pi*R^2)$

Where

Pd = power density in mW/cm2

Pout = output power to antenna in mW

G = gain of antenna in linear scale

Pi = 3.1416

R = distance between observation point and center of the radiator in cm

Pd id the limit of MPE, 1 mW/cm2 . If we know the maximum gain of the antenna and the total power input to the antenna, through the calculation, we will know the distance r where the MPE limit is reached.

5.1.2 Test Procedure

Software provided by client enabled the EUT to transmit and receive data at lowest, middle and highest channel individually.



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5.2 EUT RF Exposure Evaluation

1) For WIFI

Antenna Gain: 0.5dBi

Antenna Gain: The maximum Gain measured in fully anechoic chamber is 1.12 in linear scale.

Output Power Into Antenna & RF Exposure Evaluation Distance:

Measurement Data

802.11b mode			
Test channel	Peak Output Power (dBm)		
Lowest(2412MHz)	13.02		
Middle(2437MHz)	12.95		
Highest(2462MHz)	13.01		
	802.11g mode		
Test channel	Peak Output Power (dBm)		
Lowest(2412MHz)	17.35		
Middle(2437MHz)	17.42		
Highest(2462MHz)	17.42		
	302.11n(HT20)mode		
Test channel	Peak Output Power (dBm)		
Lowest(2412MHz)	16.18		
Middle(2437MHz)	16.31		
Highest(2462MHz)	16.10		
802.11n(HT40)mode			
Test channel	Peak Output Power (dBm)		
Lowest(2422MHz)	14.85		
Middle(2437MHz)	15.30		
Highest(2452MHz)	14.73		

802.11g(worst case)

002.118	(WOISt Gase)						
Channel	Frequency	Max Conducted	Output Power	Antenna	Power	Limit	Result
	(MHz)	Peak Output	to Antenna	Gain	Density		
		Power (dBm)	(mW)	(dBi)	at R = 20 cm		
					(mW/cm²)		
Highest	2462	17.42	55.21	0.5	0.0123	1.0	PASS

Note: 1) Refer to report No. CQASZ171001520EE-01 for EUT test Max Conducted average Output Power value.

2) $Pd = (Pout*G)/(4*Pi*R^2)=(55.21*2.1)/(4*3.1416*20^2)=0.0048$